EVHF920-S-00B



85VAC/60Hz~350VAC/50Hz 16.5V/300mA;16.5V/100mA Off-line Switching Regulator

DESCRIPTION

HF920 is a flyback regulator with a monolithic 900V MOSFET. HF920 provides excellent power regulation in AC-DC applications that require high reliability. The switching frequency can be programmed with a single resistor. Also a special frequency doubling mode, designed for strong magnetizing application, can be enabled through a simple external setup.

EVHF920-S-00B evaluation board is specially designed for a better EMC performance with very few EMI filters, which provides reference to effective PCB design for the customer. It features an off-line wide input voltage (85VAC~350VAC) with dual outputs (16.5V/300mA, 16.5V/100mA), and a highly strong anti-interference ability to external magnetic field with the use of transformer core EF20, and is very suitable for the power meter application.

EVHF920-S-00B can meets EN55022 conducted EMI requirements easily with frequency jittering function. It offers a full suite of protective features such as over-temperature **VCC** under-voltage protection. lockout. over-voltage protection, over-load protection and short-circuit protection.

ELECTRICAL SPECIFICATION

Parameter	Symbol	Value	Units
Input Voltage	V _{IN}	85 to 350	VAC
Output Voltage1	V _{OUT1}	16.5	V
Output Current1	I _{OUT1}	300	mA
Output Voltage2	V _{OUT2}	16.5	V
Output Current2	Іоит2	100	mA

FEATURES

- Wide input voltage (85VAC~350VAC)
- Fixed switching frequency, programmable up to 150kHz
- Frequency doubling operation mode
- **Excellent EMC performance**
- Over Temperature Protection
- Time-based Over Load Protection
- **Short Circuit Protection**
- Strong anti-interference ability to external magnetic field
- Power line communications

APPLICATIONS

- E-Meters
- Industrial controls
- Large appliances

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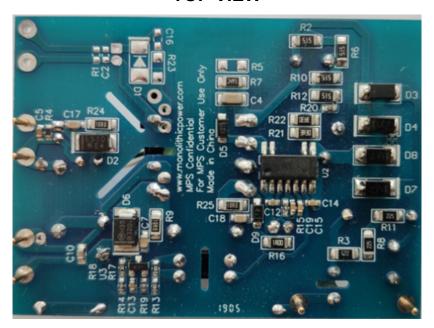
Warning: Although this board is designed to satisfy safety requirements, the engineering prototype has not been agency approved. Therefore, all testing should be performed using an isolation transformer to provide the AC input to the prototype board.



EVHF920-S-00B EVALUATION BOARD



TOP VIEW



BOTTOM VIEW

(L x W x H) 65mm x 47mm x 22mm

Board Number	MPS IC Number
EVHF920-S-00B	HF920GS



EVALUATION BOARD SCHEMATIC

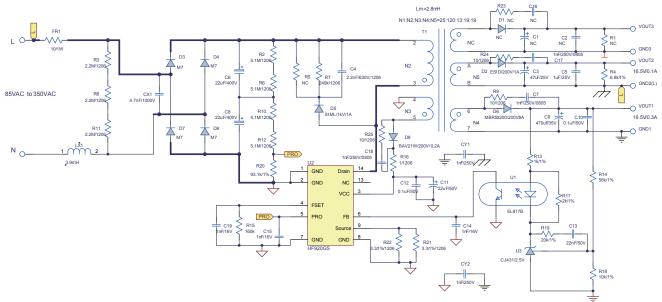


Figure 1: Schematic



EVHF920-S-00B BILL OF MATERIALS

1 C4 2.2nF Ceramic Capacitor;630V;X7R 1206 Murata GRM31BR72J222KW 2 C6,C8 22μF Electroytic Cacitor;400V DIP Rubycon 400PX22MEFC12.5X2 3 C7,C17, C18 1nF Ceramic Capacitor;250V;X7R 0805 Murata GRM21AR72E102KW 1 C9 470μF Ceramic Capacitor;35V DIP Jianghai CD263-35V470 2 C10, C12 100nF Ceramic Capacitor;50V 0603 Wurth 885012206095 1 C11 22μF Electrolytic Capacitor;50V DIP Rubycon 50YXM22MEFC5*11 1 C13 22nF Ceramic Capacitor;50V 0603 Murata GRM188R71H223KA0 3 C14,C1 5,C19 1nF Ceramic Capacitor;16V 0603 Wurth 885012206034	Qty	Ref	Value	Description	Package	Manufacturer	Manufactuer_P/N	
1 CS 1µF Capacitor;25V;X7R 0603 Murata GRM188R7/1E2/105RA 1 C4 2.2nF Ceramic Capacitor;630V;X7R 1206 Murata GRM31BR72J222KW 2 C6,C8 22µF Electroytic Capacitor;30V DIP Rubycon 400PX22MEFC12.5XZ 3 C7,C17 C18 1nF Caramic Capacitor;35V DIP Jianghai CD263-35V470 2 C10 C10 Ceramic Capacitor;50V 0603 Wurth 885012206095 1 C11 22µF Electrolytic Capacitor;50V DIP Rubycon 50YXM22MEFC5*11 1 C13 22nF Ceramic Capacitor;50V 0603 Murata GRM188R71H223KA0 3 C14,C1 1nF Ceramic Capacitor;50V 0603 Wurth 885012206034 1 CX1 4.7nF X Capacitor;16V 0603 Wurth 885012206034 1 CX1 4.7nF X Capacitor;250V;20% DIP Hongke JNK09E102MY02N 1	1	C3	47µF		DIP Jianghai		CD28L-25V47	
1 C4 2.2hF Capacitor;630V;X7R 120b Murata GRM31BR722222RW 2 C6.C8 22μF Electroytic Cactor;400V DIP Rubycon 400PX22MEFC12.5XZ 3 C7.C17, C18 1nF Ceramic Capacitor;35V DIP Jianghai CD263-35V470 1 C9 470μF Ceramic Capacitor;50V DIP Jianghai CD263-35V470 2 C10, C12 100nF Ceramic Capacitor;50V 0603 Wurth 885012206095 1 C11 22μF Electrolytic Capacitor;50V DIP Rubycon 50YXM22MEFC5*11 1 C13 22nF Ceramic Capacitor;50V 0603 Murata GRM188R71H223KA 3 C14,C1 1nF Ceramic Capacitor;50V 0603 Wurth 885012206034 1 CX1 4.7nF X Capacitor;250V;20% DIP Fara MMKP82-1000V-472F 2 CY1,CY 1nF Capacitor;250V;20% DIP Hongke JNK09E102MY02N 1 D2 <td>1</td> <td>C5</td> <td>1µF</td> <td></td> <td colspan="2">0603 Murata</td> <td>GRM188R71E2105KA12D</td>	1	C5	1µF		0603 Murata		GRM188R71E2105KA12D	
Committee	1	C4	2.2nF	Capacitor;630V;X7R	1206	Murata	GRM31BR72J222KW01L	
Capacitor;250V;X7R	2		22µF	Cacitor;400V	DIP	Rubycon	400PX22MEFC12.5X20	
1 C9 470µr Capacitor;35V DIP Jiangnal CD263-35V470 2 C10, C12 100nF Ceramic Capacitor;50V 0603 Wurth 885012206095 1 C11 22µF Electrolytic Capacitor;50V DIP Rubycon 50YXM22MEFC5*11 1 C13 22nF Ceramic Capacitor;50V 0603 Murata GRM188R71H223KA0 3 C14,C1 1nF Ceramic Capacitor;16V 0603 Wurth 885012206034 1 CX1 4.7nF X Capacitor;16V 0603 Wurth 885012206034 1 CX1 4.7nF X Capacitor;16V 0603 Wurth 885012206034 1 CX1 4.7nF X Capacitor;250V;20% DIP Hongke JNK09E102MY02N 1 D2 ES1D Schottky DIP Hongke JNK09E102MY02N 1 D3, D4, D7,D8 M7 Diode;1000V;1A SMA Diodes Taiwan 1 D6 MBRS32 Schottky	3		1nF	Capacitor;250V;X7R	0805	Murata	GRM21AR72E102KW01D	
2 C12 IO0III Capacitor;50V 0603 Wolff 885012206099 1 C11 22μF Electrolytic Capacitor;50V DIP Rubycon 50YXM22MEFC5*11 1 C13 22nF Ceramic Capacitor;50V 0603 Murata GRM188R71H223KA 3 C14,C1 5,C19 1nF Ceramic Capacitor;16V 0603 Wurth 885012206034 1 CX1 4.7nF X Capacitor;16V 0603 Wurth 885012206034 1 CX1 4.7nF X Capacitor;16V 0603 Wurth 885012206034 1 CX1 4.7nF X Capacitor;250V;20% DIP Hongke JNK09E102MY02N 2 CY1,CY 2 2 2 2 2 2 2 2 2 2 2 2 2 2 2 2 2 2 2	1		470µF	Capacitor;35V	DIP	Jianghai	CD263-35V470	
1 C11 Z2μF Capacitor;50V DIP Rubycon 501 xM2zMEFCS TI 1 C13 22nF Capacitor;50V 0603 Murata GRM188R71H223KA0 3 C14,C1 5,C19 1nF Ceramic Capacitor;16V 0603 Wurth 885012206034 1 CX1 4.7nF X Capacitor;16V DIP Fara MMKP82-1000V-472F 2 CY1,CY 2 1nF Y Capacitor;250V;20% DIP Hongke JNK09E102MY02N 1 D2 ES1D Diode;200V;1A SMA Diodes Taiwan 4 D3, D4, D7,D8 M7 Diode;200V;1A SMA Diodes Taiwan 1 D5 S1ML Diode;1000V;1A; SOD123 Diodes Taiwan 1 D6 MBRS32 Ontatky Diode;200V;0.2A; SOD123 Diodes BAV21W-7-F 1 LX1 392 3.9mH DIP Wurth 7447452392 1 FR1 10 Fuse Resistor;5%;1W DIP Yageo	2		100nF	Capacitor;50V	0603	Wurth	885012206095	
C13	1	C11	22µF	Capacitor;50V	DIP	Rubycon	50YXM22MEFC5*11	
1	1		22nF	Capacitor;50V	0603	Murata	GRM188R71H223KA01D	
2 CY1,CY 2 1nF Y Capacitor;250V;20% DIP Hongke JNK09E102MY02N 1 D2 ES1D Schottky Diode;200V;1A SMA Diodes Taiwan 4 D3, D4, D7,D8 M7 Diode;1000V;1A SMA Diodes Toshiba 1 D5 S1ML Diode;1000V;1A; SOD123 Diodes Taiwan 1 D6 MBRS322 O0T3G Schottky Diode;200V;3A SMB Onsemi MBRS3200TS3G 1 D9 BAV21W Diode;200V;0.2A; SOD123 Diodes BAV21W-7-F 1 LX1 7447452 3.9mH DIP Wurth 7447452392 1 FR1 10 Fuse Resistor;5%;1W DIP Yageo FKN1WSJT-52-10R 1 R4 6.8k Film Resistor;1% 0603 Yageo RC0603FR-076K8L 4 R2, R6, R10, R12 Film Resistor;5%;1/4W 1206 Royalohm 1206J0225T5E 1 R7 249k Film Resistor;5%;1/4W 1206	3		1nF		0603	Wurth	885012206034	
2 2 IMP Capacitor;250V;20% DIP Hongke JNR09E102MY02N 1 D2 ES1D Schottky Diode;200V;1A SMA Diodes Taiwan 4 D3, D4, D7,D8 M7 Diode;1000V;1A SMA Diodes Toshiba 1 D5 S1ML Diode;1000V;1A; SOD123 Diodes Taiwan 1 D6 MBRS32 O0T3G Schottky Diode;200V;0.2A; SOD123 Diodes BAV21W-7-F 1 LX1 7447452 392 3.9mH DIP Wurth 7447452392 1 FR1 10 Fuse Resistor;5%;1W DIP Yageo FKN1WSJT-52-10R 1 R4 6.8k Film Resistor;1% 0603 Yageo RC0603FR-076K8L 4 R10, R12 Film Resistor;5%;1/4W 1206 Yageo RC1206L515JT 3 R3, R8, R11 2.2M Film Resistor;5%;1/4W 1206 Royalohm 1206J0225T5E 1 R9, S24,R2 10 Film Resistor;1%;1/4W 1206 <	1	CX1	4.7nF	X Capacitor 1000V	DIP Fara		MMKP82-1000V-472P1	
Diode; 200V; 1A	2		1nF	1 · · · ·	DIP	Hongke	JNK09E102MY02N	
4 D7,D8 M7 Biode, 1000V, 1A SWA Biodes Tostilia 1 D5 S1ML Diode;1000V;1A; SOD123 Diodes Taiwan 1 D6 MBRS32 00T3G Schottky Diode;200V;3A SMB Onsemi MBRS3200TS3G 1 D9 BAV21W Diode;200V;0.2A; SOD123 Diodes BAV21W-7-F 1 LX1 7447452 392 3.9mH DIP Wurth 7447452392 1 FR1 10 Fuse Resistor;5%;1W DIP Yageo FKN1WSJT-52-10R 1 R4 6.8k Film Resistor;1% 0603 Yageo RC0603FR-076K8L 4 R10, R12 5.1M Film Resistor;5%;1/4W 1206 Yageo RI1206L515JT 3 R3, R8, R11 2.2M Film Resistor;5%;1/4W 1206 Yageo RC1206FR-07249KL 4 R9, R24,R2 10 Film Resistor;1%;1/4W 1206 Yageo RC1206FR-0710RL 1 R13 1k Film Resistor;1% <td>1</td> <td>D2</td> <td>ES1D</td> <td></td> <td>SMA</td> <td>Diodes</td> <td>Taiwan</td>	1	D2	ES1D		SMA	Diodes	Taiwan	
1 D6 MBRS32 00T3G 0T3G Diode;200V;3A SMB Onsemi MBRS3200TS3G 1 D9 BAV21W Diode;200V;0.2A; SOD123 Diodes BAV21W-7-F 1 LX1 7447452 392 3.9mH DIP Wurth 7447452392 1 FR1 10 Fuse Resistor;5%;1W DIP Yageo FKN1WSJT-52-10R 1 R4 6.8k Film Resistor;1% 0603 Yageo RC0603FR-076K8L 4 R2, R6, R10, R12 Film Resistor;5%;1/4W 1206 Yageo RC0603FR-076K8L 3 R3, R8, R11 Pilm Resistor;5%;1/4W Resistor;5%;1/4W 1206 Royalohm 1206J0225T5E 1 R7 249k Film Resistor;5%;1/4W Resistor;5%;1/4W 1206 Yageo RC1206FR-07249KL 3 R24,R2 5 Pilm Resistor;1%;1/4W Resistor;1%;1/4W 1206 Yageo RC0603FR-0710RL 1 R13 1k Film Resistor;1%;1/4W 1 R14 56k Film Resistor;1%;1/4W 1 R14 56k Film Resistor;1%;1/4W 1 R15 160k Film Resistor;1%;1/4W	4		M7	Diode;1000V;1A	SMA	Diodes	Toshiba	
D6	1	D5	S1ML	Diode;1000V;1A;	SOD123	Diodes	Taiwan	
1 LX1 7447452 392 3.9mH DIP Wurth 7447452392 1 FR1 10 Fuse Resistor;5%;1W DIP Yageo FKN1WSJT-52-10R 1 R4 6.8k Film Resistor;1% 0603 Yageo RC0603FR-076K8L 4 R2, R6, R10, R12 5.1M Film Resistor;5%;1/4W 1206 Yageo RI1206L515JT 3 R3, R8, R11 2.2M Film Resistor;5%;1/4W 1206 Royalohm 1206J0225T5E 1 R7 249k Film Resistor;5%;1/4W 1206 Yageo RC1206FR-07249KL 3 R9, R24,R2 5 10 Film Resistor;1%;1/4W 1206 Yageo RC1206FR-0710RL 1 R13 1k Film Resistor;1% 0603 Yageo RC0603FR-071KL 1 R14 56k Film Resistor;1% 0603 Yageo RC0603FR-0756KL 1 R15 160k Film Resistor;1% 0603 Yageo RC0603FR-07160KL	1	D6			SMB	Onsemi	MBRS3200TS3G	
1 LX1 392 3.9mH DIP Wurtn 7447452392 1 FR1 10 Fuse Resistor;5%;1W DIP Yageo FKN1WSJT-52-10R 1 R4 6.8k Film Resistor;1% 0603 Yageo RC0603FR-076K8L 4 R2, R6, R10, R12 Film Resistor;5%;1/4W 1206 Yageo RI1206L515JT 3 R3, R8, R11 2.2M Film Resistor;5%;1/4W 1206 Royalohm 1206J0225T5E 1 R7 249k Film Resistor;5%;1/4W 1206 Yageo RC1206FR-07249KL 3 R9, R24,R2 5 10 Film Resistor;1%;1/4W 1206 Yageo RC1206FR-0710RL 1 R13 1k Film Resistor;1% 0603 Yageo RC0603FR-071KL 1 R14 56k Film Resistor;1% 0603 Yageo RC0603FR-0756KL 1 R15 160k Film Resistor;1% 0603 Yageo RC0603FR-07160KL	1	D9	BAV21W	Diode;200V;0.2A;	SOD123	Diodes	BAV21W-7-F	
1 R4 6.8k Film Resistor;1% 0603 Yageo RC0603FR-076K8L 4 R2, R6, R10, R12 5.1M Film Resistor;5%;1/4W 1206 Yageo RI1206L515JT 3 R3, R8, R11 2.2M Film Resistor;5%;1/4W 1206 Royalohm 1206J0225T5E 1 R7 249k Film Resistor;5%;1/4W 1206 Yageo RC1206FR-07249KL 3 R24,R2 5 10 Film Resistor;1/4W 1206 Yageo RC1206FR-0710RL 1 R13 1k Film Resistor;1/4W 0603 Yageo RC0603FR-071KL 1 R14 56k Film Resistor;1/4W 0603 Yageo RC0603FR-0756KL 1 R15 160k Film Resistor;1/4W 0603 Yageo RC0603FR-07160KL	1	LX1		3.9mH	DIP	Wurth	7447452392	
4 R2, R6, R10, R12 5.1M Film Resistor;5%;1/4W 1206 Yageo RI1206L515JT 3 R3, R8, R1 2.2M Film Resistor;5%;1/4W 1206 Royalohm 1206J0225T5E 1 R7 249k Film Resistor;5%;1/4W 1206 Yageo RC1206FR-07249KL 3 R24,R2 5 10 Film Resistor;1%;1/4W 1206 Yageo RC1206FR-0710RL 1 R13 1k Film Resistor;1% 0603 Yageo RC0603FR-071KL 1 R14 56k Film Resistor;1% 0603 Yageo RC0603FR-0756KL 1 R15 160k Film Resistor;1% 0603 Yageo RC0603FR-07160KL	1	FR1	10	Fuse Resistor;5%;1W	DIP	Yageo	FKN1WSJT-52-10R	
4 R10, R12 5.1M Film Resistor;5%;1/4W 1206 Yageo RI1206L515JT 3 R3, R8, R11 2.2M Film Resistor;5%;1/4W 1206 Royalohm 1206J0225T5E 1 R7 249k Film Resistor;5%;1/4W 1206 Yageo RC1206FR-07249KL 3 R9, R24,R2 5 10 Film Resistor;1%;1/4W 1206 Yageo RC1206FR-0710RL 1 R13 1k Film Resistor;1% 0603 Yageo RC0603FR-071KL 1 R14 56k Film Resistor;1% 0603 Yageo RC0603FR-0756KL 1 R15 160k Film Resistor;1% 0603 Yageo RC0603FR-07160KL	1	R4	6.8k	Film Resistor;1%	0603	Yageo	RC0603FR-076K8L	
S R11 Z:ZW Resistor;5%;1/4W Royalor Royalor Royalor 1206/3022515E 1 R7 249k Film Resistor;5%;1/4W 1206 Yageo RC1206FR-07249KL 3 R9, R24,R2 5 10 Resistor;1%;1/4W 1206 Yageo RC1206FR-0710RL 1 R13 1k Film Resistor;1% 0603 Yageo RC0603FR-071KL 1 R14 56k Film Resistor;1% 0603 Yageo RC0603FR-0756KL 1 R15 160k Film Resistor;1% 0603 Yageo RC0603FR-07160KL	4	R10,	5.1M		1206	Yageo	RI1206L515JT	
1 R7 249k Resistor;5%;1/4W 1206 Yageo RC1206FR-07249KL 3 R9, R24,R2 5 10 Film Resistor;1%;1/4W 1206 Yageo RC1206FR-0710RL 1 R13 1k Film Resistor;1% 0603 Yageo RC0603FR-071KL 1 R14 56k Film Resistor;1% 0603 Yageo RC0603FR-0756KL 1 R15 160k Film Resistor;1% 0603 Yageo RC0603FR-07160KL	3		2.2M		1206	Royalohm	1206J0225T5E	
3 R24,R2 10 FIIM Resistor;1%;1/4W 1206 Yageo RC1206FR-0710RL 1 R13 1k Film Resistor;1% 0603 Yageo RC0603FR-071KL 1 R14 56k Film Resistor;1% 0603 Yageo RC0603FR-0756KL 1 R15 160k Film Resistor;1% 0603 Yageo RC0603FR-07160KL	1	R7	249k		1206 Yageo		RC1206FR-07249KL	
1 R14 56k Film Resistor;1% 0603 Yageo RC0603FR-0756KL 1 R15 160k Film Resistor;1% 0603 Yageo RC0603FR-07160KL	3	R24,R2	10		1206 Yageo		RC1206FR-0710RL	
1 R15 160k Film Resistor;1% 0603 Yageo RC0603FR-07160KL				•				
1 K16 1 Film Resistor:1% 1206 Yaqeo RC1206FR-071RI			160k					
1 R17 2k Film Resistor;1% 0603 Yageo RC0603FR-072KL			1					



EVHF920-S-00B BILL OF MATERIALS

Qty	Ref	Value	Description	Package	Manufacturer	Manufactuer_P/N	
1	R18	10k	Film Resistor;1%	0603	Yageo	RC0603FR-0710KL	
1	R19	20k	Film Resistor;1%	0603	Yageo	RC0603FR-0720KL	
1	R20	93.1k	Film Resistor;1%	0603	Yageo	RC0603FR-0793K1L	
2	R21,R22	3.3	Film Resistor;1%;1/4W	1206	Yageo	RC1206FR-073R3L	
1	U2	HF920GS	Flyback regulator with 900V integrated MOS SOIC14- 11 MPS I		HF920GS R1		
1	U1	EL817B	Photocoupler;1-Cha nnel			EL817B	
1	U3	CJ431	2.5V voltage reference	SOT23	Diodes	CJ431	
1	T1	EF20	EF20, 2.8mH, N1:N2:N3:N4:N5=25 :120:13:19:19	DIP	Emei(1)	FX0556	
6	L,N,VOUT1, VOUT2, GND1,GND2	Connector	1.0mm				
1	JP1		28mm				
1	JP2		22.6mm				
10	C1,C2,C16, D1,R1,R23,V OUT3,GND3 ,R5		NC				

Notes:

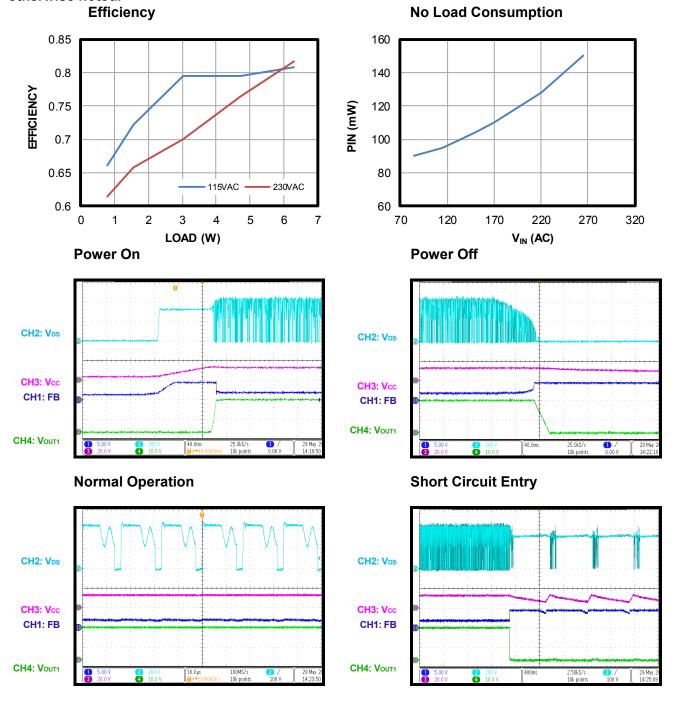
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EVB TEST RESULTS

Performance waveforms are tested on the evaluation board. VIN = 230VAC, VOUT1 = 16.5V, IOUT1 = 300mA, VOUT2 = 16.5V, IOUT2 = 100mA, TA = 25°C, unless otherwise noted.

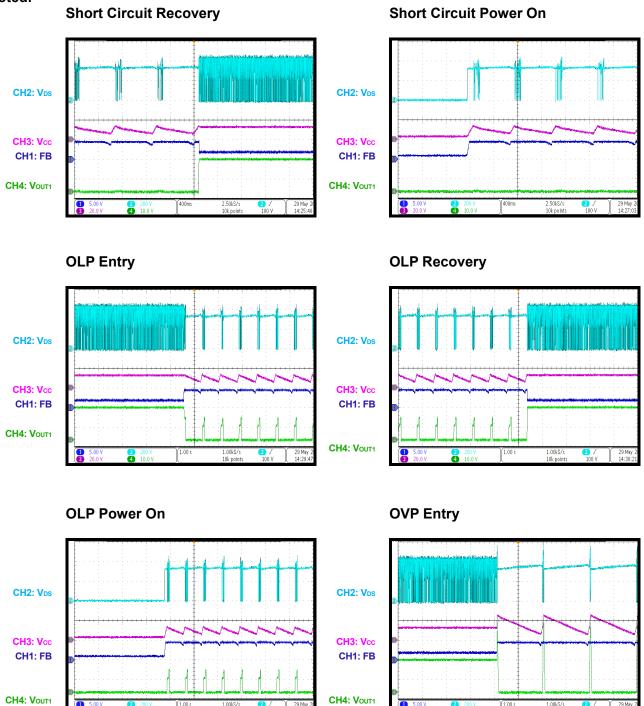




TYPICAL PERFORMANCE CHARACTERISTICS (continued)

Performance waveforms are tested on the evaluation board.

VIN = 230VAC, VOUT1 = 16.5V, IOUT1 = 300mA, VOUT2 = 16.5V, IOUT2 = 100mA, TA = 25°C, unless otherwise noted.



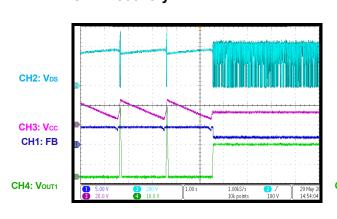


TYPICAL PERFORMANCE CHARACTERISTICS (continued)

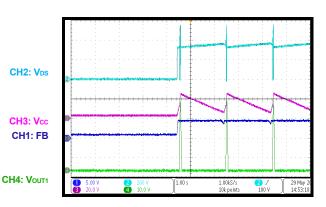
Performance waveforms are tested on the evaluation board.

VIN = 230VAC, Vout1 = 16.5V, Iout1 = 300mA, Vout2 = 16.5V, Iout2 = 100mA, TA = 25°C, unless otherwise noted.

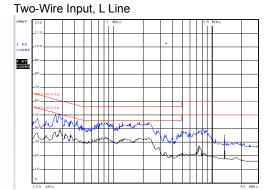
OVP Recovery



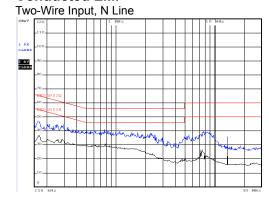
OVP Power On



Conducted EMI



Conducted EMI





PCB LAYOUT (DUAL-SIDED)

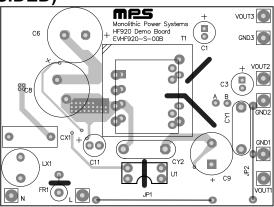


Figure 2: Top Layer

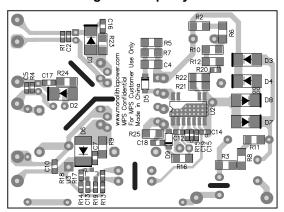


Figure 3: Bottom Layer



TRANSFORMER SPECIFICATION

Electrical Diagram

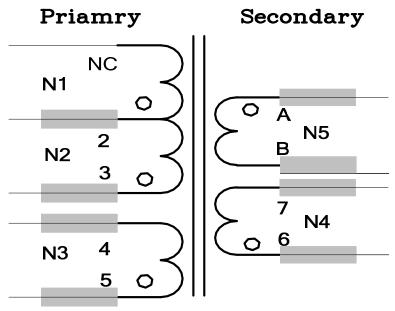


Figure 4: Transformer Electrical Diagram

Notes:

- All winding terminals are added tube; 1
- 2. N5 is flying out from the bobbin. Terminal A is labeled with white and terminal B is labeled with black;
- Remove Pin1, Pin8 and Pin10;
- Varnish the transformer.

Winding Diagram

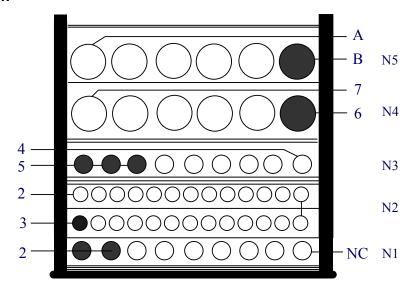


Figure 5: Winding Diagram

Winding Order



Electrical Specifications

Winding Order

Winding No.	Tape Layer No.		Start & End Mag		net Wire φ(mm)	Turns
N1	1		2—> NC	2—> NC 0.22mm*2		25
N2	1		3—⟩ 2	0.15mm*1		120
N3	1		5—〉 4	0.22mm*3		13
N4	1		6—〉 7	0.28mm*1 TIW		19
N5	1		B—〉A	0.28mm*1 TIW		19
Primary Indu	Primary Inductance		2-3, all other windings open, asured at 60kHz, 0.1VRMS			

Materials

Item	Description
1	Core: EF20, UI=2300±25%, AL=1570nH/N ² ±25% UNGAPPED
2	Bobbin: EF20 Horizontal, 6+6PIN 1SECT T-H
3	Wire: Φ0.22mm, 2UEW, Class B
4	Wire: Φ0.15mm, 2UEW, Class B
5	Wire: Φ028mm, 2UEW, Class B
6	Tape: 12.5mm(W) ×0.06mm(TH)
7	Tube: #26 BLACK; #26 CLEAR; #30 CLEAR; #23 CLEAR
8	Varnish: JOHN C. DOLPH CO, BC-346A or equivalent
9	Solder Bar: CHEN NAN: SN99.5/Cu0.5 or equivalent



CIRCUIT DESCRIPTION

EVHF920-S-00B is designed for smart power meter application with a total two output power of 6.6W. One output with GND2 connected to L line is designed for the power line communications (PLC) supply, the other is used to power the LCD for MCU.

FR1 is used to protect for the component failure or some excessive short events, also it can restrain the inrush current.

To meet the EN55022 standard, X-CAP CX1 and differential mode inductor LX1 is employed to filter EMI noise.

The diode-bridge rectifier, which is composed of D3, D4, D7 and D8, transforms input AC voltage to the dc-bus voltage.

C6 and C8 are connected in series for a high input voltage energy storage, which help to reduce line noise and protect the input against the line surge. R2, R6, R10, R12 and R20 are employed to balance the voltage on C6 and C8, and prevent the input over voltage.

The primary RCD consists of R7, C4 and D5, and it can restrain the high voltage spike to protect the MOSFET from damage.

R15 is for switching frequency options, which should be positioned far away from the data sampling frequency in power meter applications to avoid unwanted noise disturbance. Moreover, a low switching frequency is commonly used to get good thermal performance under high input voltage application. C19, typically 1nF, is used for double frequency mode selection.

C11 is the power supply capacitor for Vcc, and the ceramic C12 is used in parallel with C11 to decouple the voltage noise, it should be positioned to IC as close as possible.

R21, R22 are the current sense resistors with 1% tolerance for peak current setup.

The output electrolytic capacitor C3, C9 is used to satisfy the requirement for output voltage ripple.

R4 is dummy load to regulate the output voltage within designed value.

R14, R18 are configured to set the output voltage. The control loop composed of U1, U3, R19 and C13 feedbacks output voltage instantaneous value to FB pin. To obtain good dynamic response and high stability of system, the control loop has been carefully designed.

The input L Line is connected to GND2 for the PLC in power meter.



QUICK START GUIDE

- 1. Preset power supply to $85VAC \le V_{IN} \le 350VAC$.
- 2. Turn power supply off.
- 3. Connect the Line and Neutral terminals of the power supply output to L and N port.
- 4. Connect different loads to corresponding outputs:
 - a. Positive (+): VOUTX
 - b. Negative (-): GNDX
- 5. Turn power supply on after making connections.

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